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[Vishay Semiconductor/Diodes Division](#)
[VS-200CNQ045PBF](#)

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www.vishay.com

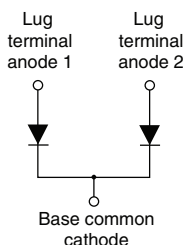
VS-200CNQ045PbF

Vishay Semiconductors

High Performance Schottky Rectifier, 200 A



TO-244



FEATURES

- 150 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

PRODUCT SUMMARY	
I _{F(AV)}	200 A
V _R	45 V
Package	TO-244
Circuit	Two diodes common cathode

DESCRIPTION

The VS-200CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	200	A
V _{RRM}		45	V
I _{FSM}	t _p = 5 μs sine	26 000	A
V _F	100 A _{pk} , T _J = 125 °C (per leg)	0.52	V
T _J	Range	-55 to 150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-200CNQ045PbF	UNITS
Maximum DC reverse voltage	V _R	45	V
Maximum working peak reverse voltage	V _{RWM}		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 116 °C, rectangular waveform	100	A
			200	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	26 000	A
		10 ms sine or 6 ms rect. pulse	1550	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 17 A, L = 1 mH	135	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical	20	A



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	100 A	$T_J = 25\text{ }^\circ\text{C}$	0.55	V
		200 A		0.73	
		100 A	$T_J = 125\text{ }^\circ\text{C}$	0.52	
		200 A		0.69	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	10	mA
		$T_J = 125\text{ }^\circ\text{C}$		800	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.27	V
Forward slope resistance	r_t	$T_J = T_J \text{ maximum}$		2.0	$m\Omega$
Maximum junction capacitance per leg	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		5200	pF
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s

Note

(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T_J, T_{Stg}	- 55	-	150	$^\circ\text{C}$	
Thermal resistance, junction to case	per leg	-	-	0.38	$^\circ\text{C}/\text{W}$	
	per module	-	-	0.19		
Thermal resistance, case to heatsink	R_{thCS}	-	0.10	-		
Weight		-	68	-	g	
			2.4			
Mounting torque		35.4 (4)	-	53.1 (6)	lbf · in (N · m)	
Mounting torque center hole		30 (3.4)	-	40 (4.6)		
Terminal torque		30 (3.4)	-	44.2 (5)		
Vertical pull		-	-	80	lbf · in	
2" lever pull		-	-	35		

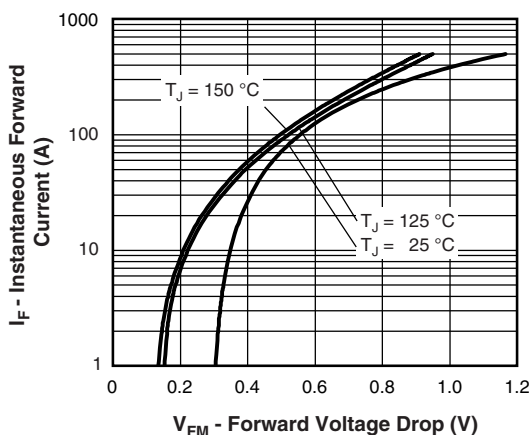


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

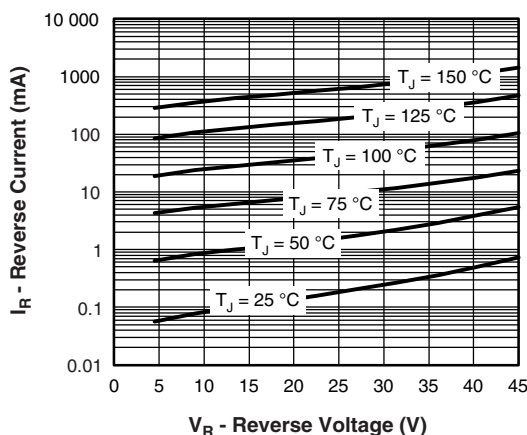


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)



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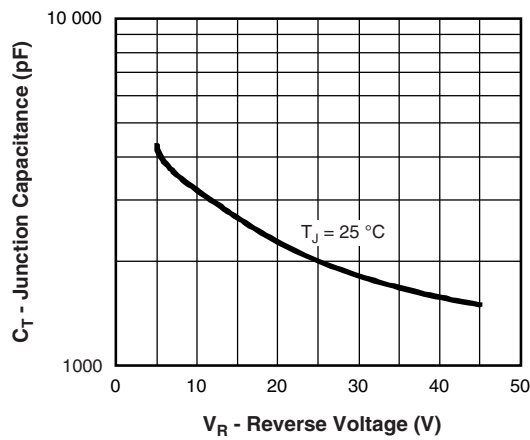


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

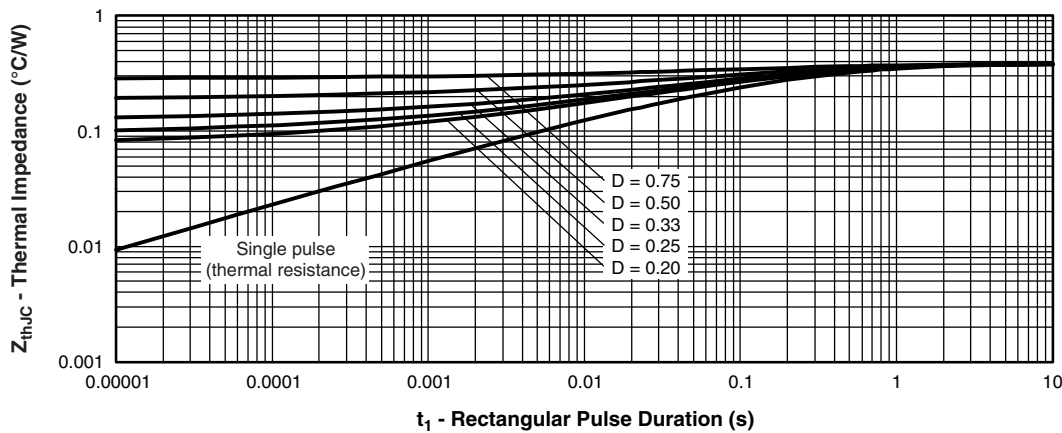


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

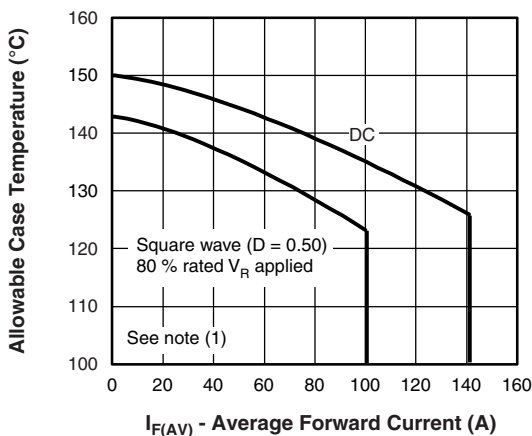


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

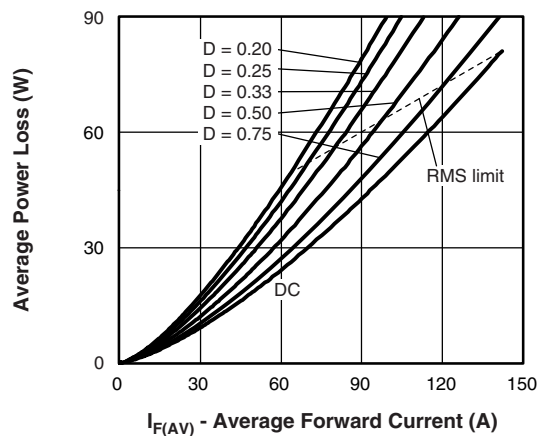


Fig. 6 - Forward Power Loss Characteristics (Per Leg)



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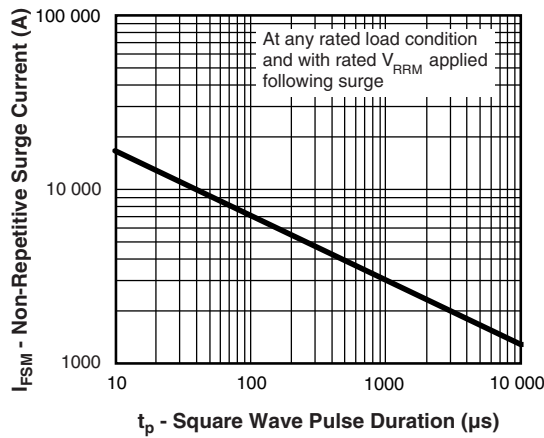


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

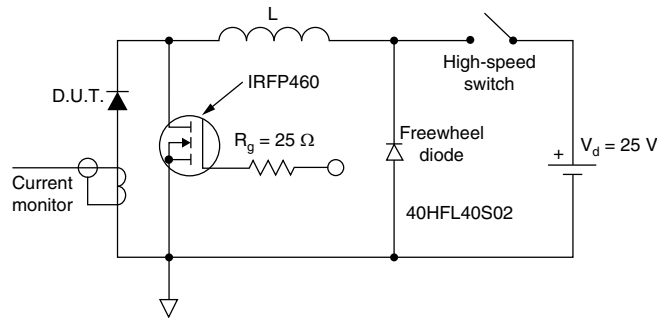


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
- P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

ORDERING INFORMATION TABLE

Device code	VS-	20	0	C	N	Q	045	PbF
	①	②	③	④	⑤	⑥	⑦	⑧

- 1** - Vishay Semiconductors product
- 2** - Average current rating (x 10)
- 3** - Product silicon identification
- 4** - C = Circuit configuration
- 5** - N = Not isolated
- 6** - Q = Schottky rectifier diode
- 7** - Voltage rating (045 = 45 V)
- 8** - Lead (Pb)-free

LINKS TO RELATED DOCUMENTS

Dimensions	www.vishay.com/doc?95021
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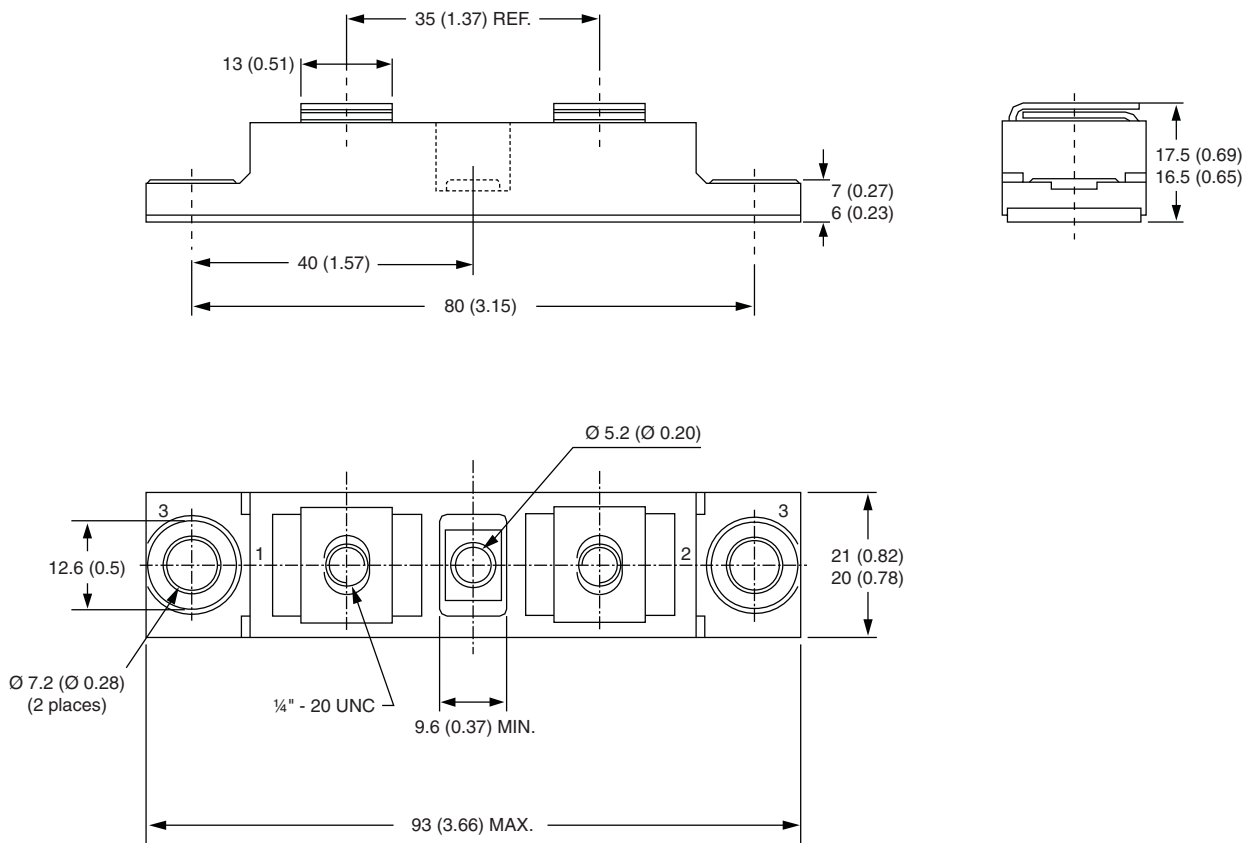


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Outline Dimensions
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TO-244

DIMENSIONS in millimeters (inches)





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